



#### 250V P-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

BV <sub>DSS</sub>	RDS(ON) Max	I <sub>D Max</sub> T <sub>A</sub> = +25°C
-250V	$14\Omega @ V_{GS} = -10V$	-0.26A
-250V	18Ω @ V <sub>GS</sub> = -3.5V	-0.23A

### **Description and Applications**

This new generation MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- · General Purpose Interfacing Switch
- Load Switching
- Battery Management Application
- Power Management Functions

## **Features and Benefits**

- 0.6mm Profile Ideal for Low-Profile Applications
- PCB Footprint of 4mm<sup>2</sup>
- Low Gate Threshold Voltage
- Low On-Resistance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

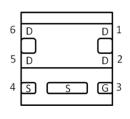
#### **Mechanical Data**

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.0065 grams (Approximate)

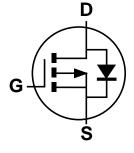
#### U-DFN2020-6 (Type E)



**Bottom View** 



Pin Out Bottom View



**Equivalent Circuit** 

### Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Quantity per Reel
DMP25H18DLFDE-7	H8	7	3,000
DMP25H18DLFDE-13	H8	13	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/



## **Marking Information**

Site 1



H8 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key

Year	2014		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	В		Н		J	K	L	М	N	0	Р	R
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Site 2



H8 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 0 = 2020) W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key

Year	2014	 2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	4	 0	1	2	3	4	5	6	7	8	9

Week	1-26	27-52	53
Code	A-Z	a-z	z

Internal Code	Sun	Mon	Tue	Wed	Thu	Fri	Sat
Code	Т	U	V	W	Х	Y	Z



# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			VDSS	-250	V
Gate-Source Voltage	V <sub>GSS</sub>	±40	V		
Continuous Drain Current (Note 6) V <sub>GS</sub> = -10V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	lo	-0.26 -0.21	А
Pulsed Drain Current (10µs Pulse, Duty Cycle ≦1%)	I <sub>DM</sub>	-1.0	Α		
Maximum Body Diode Continuous Current (Note 6)			Is	-0.26	Α

## **Thermal Characteristics**

Characteristic		Symbol	Value	Unit	
Total Dawer Dissination	(Note 5)	D-	0.6	W	
Total Power Dissipation	(Note 6)	PD	1.4	VV	
Thermal Resistance, Junction to Ambient	(Note 5)	Б	191		
mermai Resistance, Junction to Ambient	(Note 6)	$R_{ heta JA}$	86	°C/W	
Thermal Resistance, Junction to Case (Note 6		Rejc	17		
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BVDSS	-250		_	V	$V_{GS} = 0V, I_{D} = -1mA$
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	IDSS	_	_	-1	μΑ	V <sub>DS</sub> = -250V, V <sub>GS</sub> = 0V
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 40V$ , $V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(TH)	-0.5	-1.7	-2.5	V	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = -1mA
Static Drain-Source On-Resistance	Pro/our		10	14	Ω	V <sub>G</sub> S = -10V, I <sub>D</sub> = -200mA
Static Drain-Source On-Resistance	RDS(ON)		13	18	12	$V_{GS} = -3.5V, I_D = -100mA$
Diode Forward Voltage	$V_{SD}$	_	-0.8	-1.2	V	$V_{GS} = 0V, I_{S} = -200mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	81	_	pF	.,
Output Capacitance	Coss	_	14	_	pF	$V_{DS} = -25V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	4	_	pF	1 = 1.0WH2
Gate Resistance	Rg	_	13	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg	_	2.8	_	nC	
Gate-Source Charge	Qgs	_	0.3	_	nC	V <sub>DS</sub> = -25V, I <sub>D</sub> = -200mA
Gate-Drain Charge	Q <sub>gd</sub>	_	0.6	_	nC	
Turn-On Delay Time	td(ON)	_	7.5	_	ns	
Turn-On Rise Time	t <sub>R</sub>	_	25	_	ns	V <sub>DS</sub> = -30V, I <sub>D</sub> = -200mA
Turn-Off Delay Time	tD(OFF)	_	124	_	ns	$V_{GS} = -10V$ , $R_G = 50\Omega$
Turn-Off Fall Time	t <sub>F</sub>	_	95	_	ns	
Reverse Recovery Time	trr	_	85	_	ns	I- 4.00 di/dt 4.000/:
Reverse Recovery Charge	Q <sub>RR</sub>	_	294	_	μC	I <sub>F</sub> = -1.0A, di/dt = 100A/μs

Notes:

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate.7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to production testing.

DMP25H18DLFDE Datasheet number: DS37298 Rev. 4 - 2

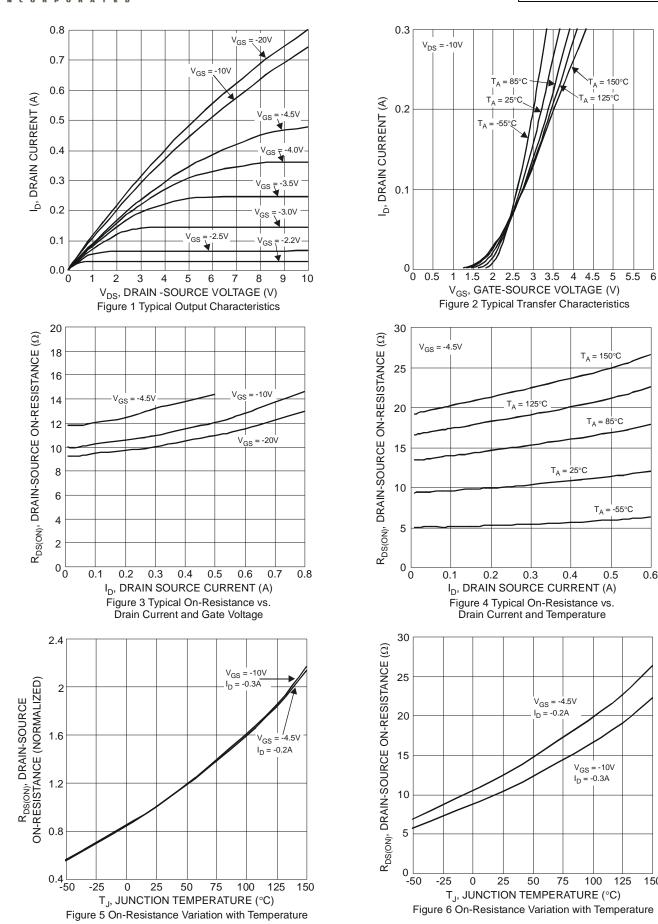
A = 150°C

T<sub>A</sub> = -55°C

0.5

0.6





125



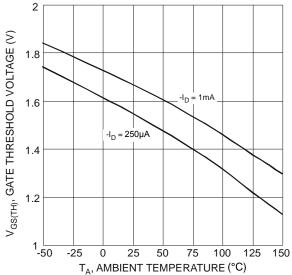
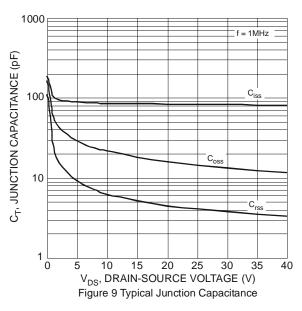
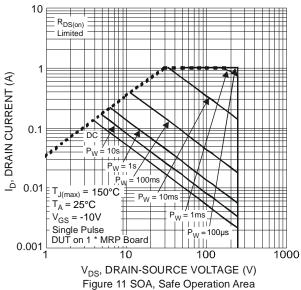
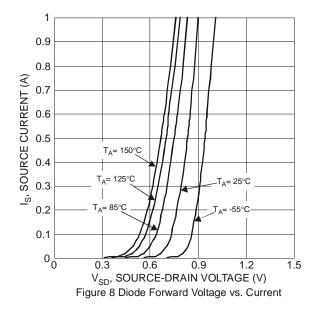
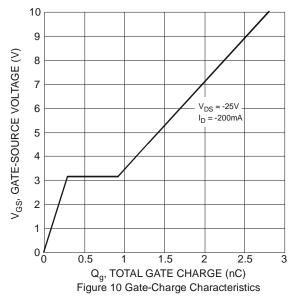


Figure 7 Gate Threshold Variation vs. Ambient Temperature

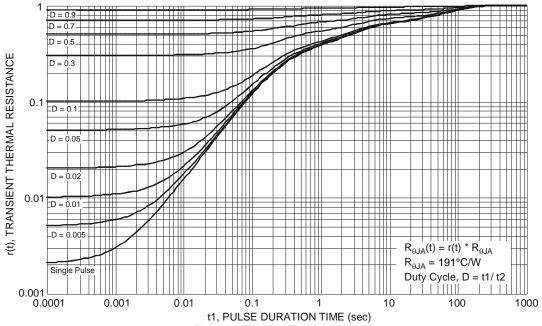










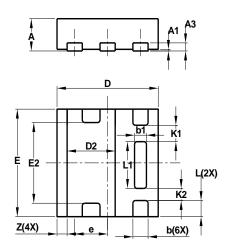




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### U-DFN2020-6 (Type E)

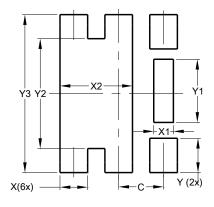


U-DFN2020-6								
Type E								
Dim	Min	Max	Тур					
Α	0.57	0.63	0.60					
A1	0	0.05	0.03					
А3	_	_	0.15					
b	0.25	0.35	0.30					
b1	0.185	0.285	0.235					
D	1.95	2.05	2.00					
D2	0.85	1.05	0.95					
Е	1.95	2.05	2.00					
E2	1.40	1.60	1.50					
е	_	_	0.65					
L	0.25	0.35	0.30					
L1	0.82	0.92	0.87					
K1	_	_	0.305					
K2	_	_	0.225					
Z	_	_	0.20					
All	Dimens	ions in r	nm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### U-DFN2020-6 (Type E)



Dimensions	Value (in mm)
С	0.650
X	0.400
X1	0.285
X2	1.050
Y	0.500
Y1	0.920
Y2	1.600
Y3	2 300



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Datasheet number: DS37298 Rev. 4 - 2

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